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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/597,987	10/18/2006	Ingo Schwirtlich	06093	8865
	7590 09/14/201 CHULTZ & MACDOI	EXAMINER		
1727 KING STI SUITE 105		SONG, MATTHEW J		
ALEXANDRIA, VA 22314			ART UNIT	PAPER NUMBER
			1714	
			MAIL DATE	DELIVERY MODE
			09/14/2010	PAPER

# Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary		Applic	ation No.	Applicant(s)	Applicant(s)			
		10/597	<sup>7</sup> ,987	SCHWIRTLICH E	SCHWIRTLICH ET AL.			
		Exami	ner	Art Unit				
		MATTH	IEW J. SONG	1714				
Period fo	The MAILING DATE of this communic or Reply	ation appears on	the cover sheet wit	th the correspondence a	ddress			
WHIC - Exter after - If NC - Failu Any r	ORTENED STATUTORY PERIOD FOR CHEVER IS LONGER, FROM THE MA asions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this community period for reply is specified above, the maximum stature to reply within the set or extended period for reply with the set or extended period for reply wi	ILING DATE OF 37 CFR 1.136(a). In no ication. tory period will apply an II, by statute, cause the	THIS COMMUNIC o event, however, may a red d will expire SIX (6) MON' application to become AB.	CATION.  eply be timely filed  THS from the mailing date of this ANDONED (35 U.S.C. § 133).				
Status								
1)	Responsive to communication(s) filed	on 28 June 2010	)					
•	•	)∏ This action is						
′=		<i>'</i> —		ers prosecution as to th	e merits is			
٠,١	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositi	on of Claims	·	•					
- 4)⊠	Claim(s) <u>25-45</u> is/are pending in the a	polication						
•	4a) Of the above claim(s) is/are withdrawn from consideration.							
	5) Claim(s) is/are allowed.							
•	Claim(s) <u>25-45</u> is/are rejected.							
	Claim(s) is/are objected to.							
•	Claim(s) are subject to restriction	on and/or electio	n requirement.					
	on Papers		•					
	•	<b>-</b>						
-	The specification is objected to by the		h\□ abiaatad ta l	ou the Everniner				
10)	The drawing(s) filed on is/are: a		· -	-				
	Applicant may not request that any objecti		· ·		SED 4 404/4)			
11)	Replacement drawing sheet(s) including the coath or declaration is objected to be				, ,			
	•	y the Examiner.	Note the attached	Office Action of form P	10-102.			
Priority (	ınder 35 U.S.C. § 119							
12)	Acknowledgment is made of a claim fo	r foreign priority	under 35 U.S.C. §	119(a)-(d) or (f).				
a)[	☐ All b)☐ Some * c)☐ None of:							
	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
	3. Copies of the certified copies of the priority documents have been received in this National Stage							
	application from the Internationa	al Bureau (PCT F	Rule 17.2(a)).					
* S	See the attached detailed Office action	for a list of the ce	ertified copies not	received.				
Attachmen			_					
	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PT0	2 049)		ummary (PTO-413) )/Mail Date				
	e of Draftsperson's Patent Drawing Review (PTC nation Disclosure Statement(s) (PTO/SB/08)	J- <del>34</del> 0)		formal Patent Application				
Paper No(s)/Mail Date 6) Other:								

#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

2. Claims 25-29, 32-35, 39 and 41 are rejected under 35 U.S.C. 103(a) as being unpatentable over Freedman et al (US 4,968,380) in view of Arvidson (US 2003/0131783).

Referring to claim 25, Freedman et al teaches a process for conveying solid particles through at least one pipe or pipe system 60, 90 having a curve (82 is a chamber which connects pipe 60 and 90 and the chamber is curved, thus the chamber 82 is curved and part of the pipe system and a pipe is broadly interpreted as a hollow body for conducting a liquid, gas or solid) where in fluid (Ar gas) is used for conveying the solid particles (Fig 2, col 3, ln 35-60; col 4, ln

35-65; col 5, ln 1-40). Freedman et al also teaches that the silicon melt replenishment system is intended to operate with spherical silicon beads but the system can also be operated using irregularly shaped silicon particles having a specific dimensional characteristic (col 5, ln 60-68).

Freedman et al does not explicitly teach conveying irregular geometry particles as first solid particles and admixing them second solid particles of regular geometry. Freedman et al does teach the system can operate with spherical, regularly shaped silicon particles and irregularly shaped particles (col 5, ln 60-68). Therefore, It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Freedman et al by combination regular and irregularly shaped particles because combination of known equivalents for the same purpose is prima facie obvious (MPEP 2144.06) and combinations of spherical beads and irregular silicon chunks is conventionally known in the art to be used to form silicon melts, as evidenced by Arvidson (US 2003/0131783) in paragraph [0019].

Referring to claim 26, the combination of Freedman et al and Arvidson et al teaches irregularly shaped particles ('380 col 5, ln 60-68). The combination of Freedman et al and Arvidson et al does not teach polygonal geometry. Changes in shape are prima facie obvious (MPEP 2144.04); therefore the use of polygonal geometry would have been obvious to one of ordinary skill in the art.

Referring to claim 27, the combination of Freedman et al and Arvidson et al teaches spherical particles ('380 col 5, ln 60-68).

Referring to claim 28, the combination of Freedman et al and Arvidson et al teaches the apparatus is intended to be used with spherical beads, however can be used with silicon particles of irregular geometry ('380 col 5, ln 60-68). Therefore, It would have been obvious to a person

of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al by using a high percentage (50-99%) of spherical beads because the invention is intended be used with spherical beads.

Referring to claim 29, the combination of Freedman et al and Arvidson et al teaches Ar gas fluid ('380 col 5, ln 20-40).

Referring to claim 32, the combination of Freedman et al and Arvidson et al teaches a L/D ranges from about 1 to 1.2 ('380 col 5, ln 60-68), which is within the claimed range.

Referring to claim 33, the combination of Freedman et al and Arvidson et al is silent to the maximum length of the solid particle is the radius of the pipe. It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al by using particles with a maximum length equal to the radius of the pipe such that particles can flow through the pipe without clogging the pipe. Also, changes in size are prima facie obvious (MPEP 2144.04).

Referring to claim 34-35, the combination of Freedman et al and Arvidson et al teaches irregularly shaped pieces obtained by breaking CVD polysilicon logs ('783 [0020]).

Referring to claim 39, the combination of Freedman et al and Arvidson et al teaches the particles are accelerated by the Ar gas (\*380 col 5, ln 1-60).

Referring to claim 41, the combination of Freedman et al and Arvidson et al teaches Argon gas ('380 col 5, ln 1-60).

3. Claims 36-38 are rejected under 35 U.S.C. 103(a) as being unpatentable over Freedman et al (US 4,968,380) in view of Arvidson (US 2003/0131783) as applied to claims 25-29, 32-35, 39 and 41 above, and further in view of Nagai et al (US 5,900,055).

Referring to claim 36, the combination of Freedman et al and Arvidson et al teaches all of the limitations of claim 36, as discussed above, except the silicon melt is doped using doping elements present in the particles of irregular geometry.

In a method of growing crystals from a silicon melt, Nagai et al teaches a dopant feeding apparatus for charging a predetermined amount of dopant and dopant containing granular silicon (col 2, ln 1-10 and col 7, ln 1-67).

It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al by supplying a particles containing a dopant, as taught by Nagai et al, to produce a crystal having a desired dopant concentration and resistivity ('055 col 1, ln 5-67).

Referring to claim 37, the combination of Freedman et al and Arvidson et al and Nagai et al teaches boron and phosphorous ('055 col 1, ln 20-40).

Referring to claim 38, the combination of Freedman et al and Arvidson et al and Nagai et al does not teach the claimed concentration of the dopant particles. However, concentration is well known in the art to be a result effective variable; therefore It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al and Nagai et al by optimizing the concentration of dopant particles by conducting routine experimentation of a result effective variable to obtain a desired resistivity (MPEP 2144.05). Also, the combination of dopant particles with different

concentrations would have been obvious to one of ordinary skill in the art because combinations of known materials suitable for their intended purpose is prima facie obvious (MPEP 2144.07).

4. Claims 30, 31, 40, 42-45 are rejected under 35 U.S.C. 103(a) as being unpatentable over Freedman et al (US 4,968,380) in view of Arvidson (US 2003/0131783) as applied to claims 25-29, 32-35, 39 and 41 above, and further in view of Mackintosh et al (US 6,562,132).

The combination of Freedman et al and Arvidson et al teaches all of the limitations of claim 30, as discussed above, except the fluid is supplied in pulses.

In a method of crystal growth, Mackintosh et al teaches silicon particles are introduced to a crucible to replenish a melt in the crucible during a growth process, and it is common practice to deliver the particles in predetermined intermittent basis according to the rate of consumption of the melt so as to maintain the level of the melt within predetermined limits (col 1, ln 10-65).

It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al by supplying the fluid intermittently (pulses) to supply the particles in a predetermined intermittent basis according to the rate of consumption of the melt so as to maintain the level of the melt within predetermined limits, as taught by Mackintosh et al.

Referring to claim 30-31, the pulses are either regular or irregular.

Referring to claim 40, the combination of Freedman et al and Arvidson et al teaches a conical deflecting element 66 ('380 col 3, ln 35-65). The combination of Freedman et al and Arvidson et al does not teach a baffle element surrounding the pipe, passing around the outer edge in the area of the melt and having a spherical surface section geometry. Mackintosh et al

teaches particles impinge upon a deflect which deflects them back down toward a conical upper surface of an umbrella shaped feed director, which clearly suggests a baffle surrounding a feed tube and passing particles around the outer edge in the area of the melt, and the particles slide down the director surface and fall into the melt along the outer edge (Fig 1-2 and col 5, ln 35-67 and col 8, ln 1-67). Mackintosh et al also teaches the inclined surface reduces the velocity of the particles so the particles will cause little or no splashing, thus eliminating the mushroom problem (col 8, ln 1-40). It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al and Arvidson et al by using the director (baffle) taught by Mackintosh et al to reduce splashing of particles, thereby avoiding the mushroom problem. As to the spherical surface section geometry, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al, Arvidson et al and Mackintosh et al by using a spherical surface section geometry because changes in shape are prima facie obvious (MPEP 2144.04) and the combination of Freedman et al, Arvidson et al and Mackintosh et al teaches an umbrella shape which suggests a spherical surface geometry.

Referring to claim 42, the combination of Freedman et al, Arvidson et al and Mackintosh et al teaches an EFG process where the process may be used to grow shaped bodies with rectangular or circular configurations ('132 col 10, ln 55-67 and col 11, ln 1-40), thus one of ordinary skill the art would have found obvious to produce wafers as the shaped body because changes in shape are prima facie obvious (MPEP 2144.04) and a wafer shape is conventionally known in the art.

Referring to claim 44, the combination of Freedman et al, Arvidson et al and Mackintosh et al teaches an after heater **190** surrounding the direction and deflector, thus the deflector and director are expected to be heated. The combination of Freedman et al, Arvidson et al and Mackintosh et al is silent to the temperature, however temperature is well known in the art to be result effective variable; therefore It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Freedman et al, Arvidson et al and Mackintosh et al by optimizing the temperature by conducting routine experimentation of a result effective variable. (MPEP 2144.05).

Referring to claim 43 and 45, the combination of Freedman et al, Arvidson et al and Mackintosh et al teaches the dimensions of the deflector and direction and angles may be may be to adjust the velocity of particles ('132 col 10, ln 55 to col 11, ln 10), which clearly suggests the adapting the geometry. As to claim 45, changes in the shape of the deflector and director would have been obvious to one of ordinary skill in the art to control the distribution and velocity of particles.

# Response to Arguments

5. Applicant's arguments filed 6/28/2010 have been fully considered but they are not persuasive.

Applicant's argument that Freedman et al does not teach forming a mixture of spherical and irregularly shaped particles is noted but not found persuasive. Freedman et al teaches the using regularly shaped particles (spherical) and the system can also be operated using irregularly shaped silicon particles (col 5, ln 1-67). Therefore, It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Freedman et al by using a

combination of known materials suitable for their intended purpose of replenishing a melt.

(MPEP 2144.07). Furthermore, combinations of regularly shape and irregularly shaped silicon materials is known in the art, as evidenced by Arvidson.

Applicant's argument that Freedman et al teaches straight pipes without a kink or curve is noted but not found persuasive. Freedman et al teaches chamber 82 which is broadly interpreted as being part of the pipe or pipe system because a "pipe" is merely a hollow body for conducting a liquid, gas or finely divided solid according to the Merriam-Webster dictionary (See Merriam-Webster dictionary definition of pipe). Therefore Freedman et al does teach a pipe or pipe system with a curve. Furthermore, the pipe 94 has a bend is part of the pipe system for transporting the particles. It is also noted that Nagai et al (US 5,900,055) teaches the feed pipe 10 is constricted at a lower portion near the crucible, which clearly suggests a kink.

Applicant's arguments regarding claim 32 regarding the claimed system being able to utilize irregular particles up to a L/D ratio up to 3 is noted but not found persuasive. The claim merely requires a L/D ratio of less than or equal to 3, thus a ratio of 1.2 would be within the claimed range.

Applicant's arguments regarding Arvidson et al is noted but not found persuasive.

Arvidson et al is merely provided to show that combinations of regularly shaped silicon and irregularly shaped silicon is known in the art to be used to form a silicon melt. Also, Arvidson et al teaches a high packing density can be achieved when mixing materials of different shape, which is motivation for one skilled in the to combine regular and irregularly shaped silicon. The Examiner maintains that Freedman et al teaches the silicon replenishment system can be used for

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regular and irregularly shaped particles, thus the combination of regular and irregular shaped particles would have been obvious to one of ordinary skill in the art, as discussed above.

### Conclusion

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to MATTHEW J. SONG whose telephone number is (571)272-1468. The examiner can normally be reached on M-F 11:00-7:00.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Kornakov can be reached on 571-272-1303. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Matthew J Song Examiner Art Unit 1714

/Matthew J Song/ Examiner, Art Unit 1714